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April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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## MOS FIELD EFFECT POWER TRANSISTOR

# Phase-out/Discontinued 2SK1595

# SWITCHING N-CHANNEL POWER MOS FET INDUSTRIAL USE

#### **DESCRIPTION**

The 2SK1595 is N-channel MOS Field Effect Transistor designed for solenoid, motor and lamp driver.

#### **FEATURES**

- Low On-state Resistance
  - RDS(on)  $\leq$  30 m $\Omega$  (VGS = 10 V, ID = 15 A) RDS(on)  $\leq$  50 m $\Omega$  (VGS = 10 V, ID = 15 A)
- Low Ciss Ciss = 2 000 pF TYP.
- Built-in G-S Gate Protection Diode

#### **QUALITY GRADE**

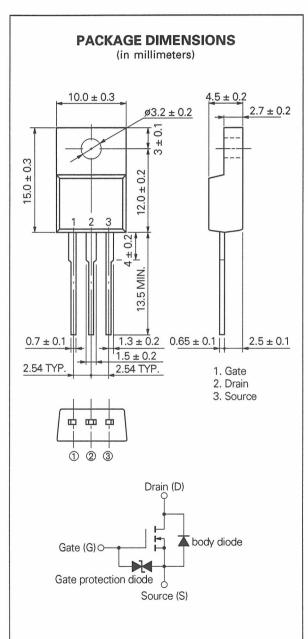
#### Standard

Please refer to "Quality grade on NEC Semiconductor Devices" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

#### ABSOLUTE MAXIMUM RATINGS (Ta = 25 °C)

Drain to Source Voltage	Voss	30	V
Gate to Source Voltage	VGSS (A	±20	V
Drain Current (DC)	D(DC)	±30	Α
Drain Current (pulse)	D(pulse)	±120	Α
Total Power Dissipation (Tc = 25 °C)	PT1	35	W
Total Power Dissipation (Ta = 25 °C)	PT2	2.0	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	-55 to +150	°C

\* PW  $\leq$  10  $\mu$ s, Duty Cycle  $\leq$  1 %



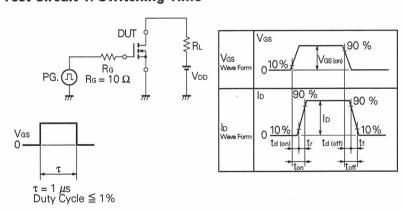




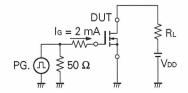
### ELECTRICAL CHARACTERISTICS (Ta = 25 °C)

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Drain to Source On-state Resistance	Ros(on)		22	30	mΩ	Vgs = 10 V, lp = 15 A
Drain to Source On-state Resistance	RDS(on)		30	50	mΩ	Vgs = 4 V, ID = 15 A
Gate to Source Cutoff Voltage	Vgs(off)	1.0		2.5	V	Vps = 10 V, lp = 1 mA
Forward Transfer Admittance	yfs	12	25		S	Vps = 10 V, lp = 15 A
Drain Leakage Current	loss			10	μΑ	Vps = 30 V, Vgs = 0
Gate to Source Leakage Current	Igss			±10	μΑ	Vgs = ±20 V, Vps = 0
Input Capacitance	Ciss		2 000		pF	V <sub>DS</sub> = 10 V V <sub>GS</sub> = 0 f = 1 MHz
Output Capacitance	Coss		1 200		pF	
Reverse Transfer Capacitance	Crss		400		pF	
Turn-On Delay Time	td(on)		45		ns	$V_{GS(on)} = 10 \text{ V}$ $V_{DD} = 15 \text{ V}$ $I_{D} = 15 \text{ A}, \text{ Rg} = 10 \Omega$ $R_{L} = 1.0 \Omega$
Rise Time	tr		500		ns	
Turn-Off Delay Time	td(off)		270		ns	
Fall Time	tr		220		ns	
Total Gate Charge	QG		55		nC	Vgs = 10 V ID = 30 A VDD = 24 V
Gate to Source Charge	Qgs		10		nC	
Gate to Drain Charge	Qgp		20		nC	
Diode Forward Voltage	Vsp		1.1		V	IF = 30 A, VGS = 0
Reverse Recovery Time	trr		75		ns	I <sub>F</sub> = 30 A, V <sub>GS</sub> = 0 di/dt = 50 A/μs
Reverse Recovery Charge	Qrr		100		nC	

### **Test Circuit 1: Switching Time**

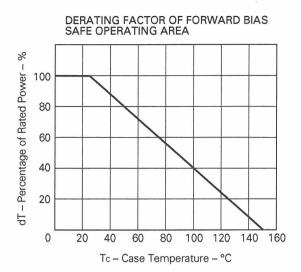


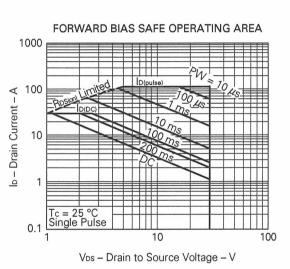
**Test Circuit 2: Gate Charge** 



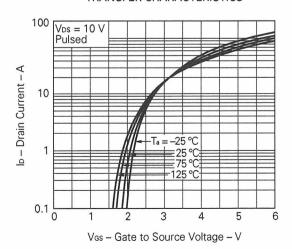


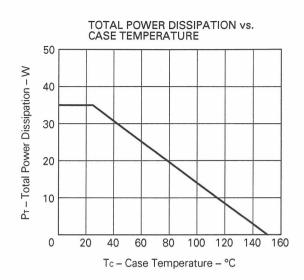
#### TYPICAL CHARACTERISTICS (Ta = 25 °C)

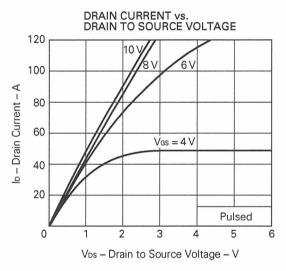


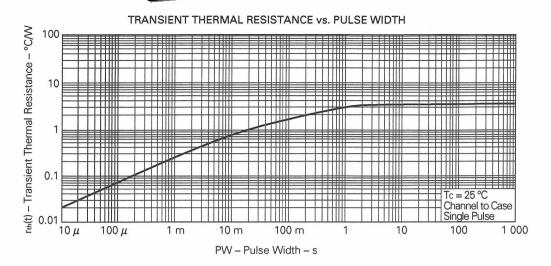


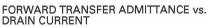


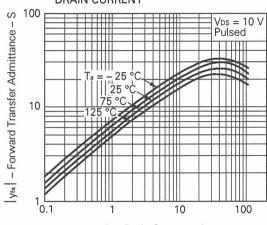




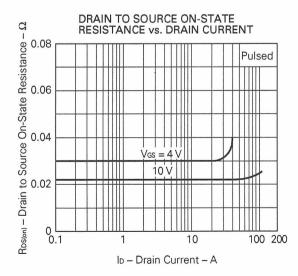




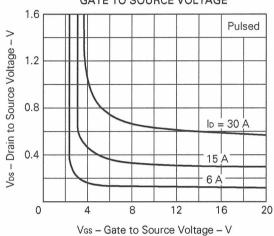


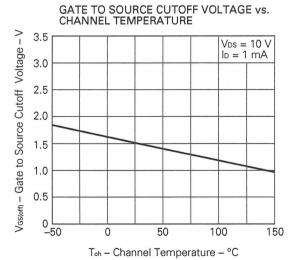


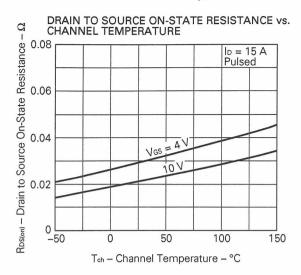
#### lo - Drain Current - A

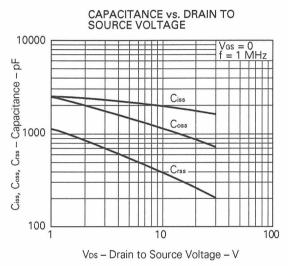


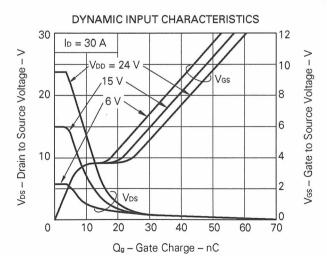
## DRAIN TO SOURCE VOLTAGE vs. GATE TO SOURCE VOLTAGE

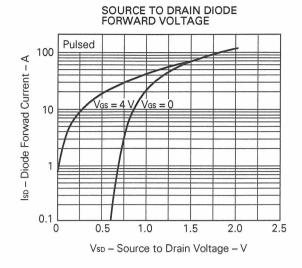


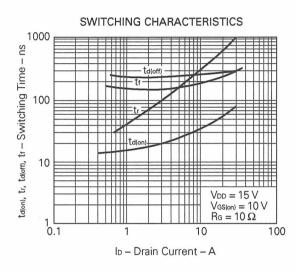
















#### Reference

Application note name	No.
Safe operating area of Power MOS FET.	TEA-1034
Application circuit using Power MOS FET.	TEA-1035
Quality control of NEC semiconductors devices.	TEI-1202
Quality control guide of semiconductors devices.	MEI-1202
Assembly manual of semiconductors devices.	IEI-1207

[MEMO]



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